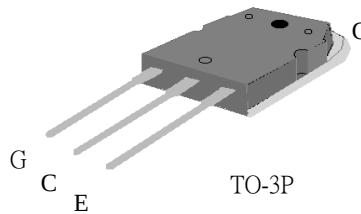


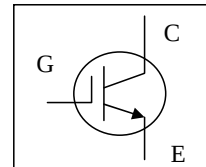


Features

- ▼ High Speed Switching
- ▼ Low Saturation Voltage
 $V_{CE(sat),typ.}=1.8V@I_C=20A$
- ▼ RoHS Compliant & Halogen-Free



V_{CES}	600V
I_C	20A



Absolute Maximum Ratings@ $T_J=25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter	Rating	Units
V_{CES}	Collector-Emitter Voltage	600	V
V_{GE}	Gate-Emitter Voltage	± 20	V
$I_C@T_C=25^{\circ}C$	Collector Current	40	A
$I_C@T_C=100^{\circ}C$	Collector Current	20	A
I_{CM}	Pulsed Collector Current ¹	160	A
$P_D@T_C=25^{\circ}C$	Maximum Power Dissipation	125	W
T_{STG}	Storage Temperature Range	-55 to 150	$^{\circ}C$
T_J	Operating Junction Temperature Range	150	$^{\circ}C$

Notes:

1. Pulse width limited by Max. junction temperature .

Thermal Data

Symbol	Parameter	Value	Units
R_{thj-c}	Thermal Resistance Junction-Case	1	$^{\circ}C/W$
R_{thj-a}	Thermal Resistance Junction-Ambient	40	$^{\circ}C/W$

Electrical Characteristics@ $T_J=25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
I_{GES}	Gate-to-Emitter Leakage Current	$V_{GE}=\pm 20V, V_{CE}=0V$	-	-	± 100	nA
I_{CES}	Collector-Emitter Leakage Current	$V_{CE}=600V, V_{GE}=0V$	-	-	500	μA
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$V_{GE}=15V, I_C=20A$	-	1.8	2.5	V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$V_{GE}=15V, I_C=35A$	-	2	2.7	V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{CE}=V_{GE}, I_C=250\mu A$	2	-	6	V
Q_g	Total Gate Charge	$I_C=20A$	-	100	160	nC
Q_{ge}	Gate-Emitter Charge	$V_{CE}=480V$	-	24	-	nC
Q_{gc}	Gate-Collector Charge	$V_{GE}=15V$	-	40	-	nC
$t_{d(on)}$	Turn-on Delay Time	$V_{CE}=480V,$ $I_C=20A,$	-	50	-	ns
t_r	Rise Time	$V_{GE}=15V,$ $R_G=5\Omega,$	-	20	-	ns
$t_{d(off)}$	Turn-off Delay Time	Inductive Load	-	135	-	ns
t_f	Fall Time		-	190	380	ns
E_{on}	Turn-On Switching Loss		-	0.3	-	mJ
E_{off}	Turn-Off Switching Loss		-	0.9	-	mJ
C_{ies}	Input Capacitance	$V_{GE}=0V$	-	3400	5440	pF
C_{oes}	Output Capacitance	$V_{CE}=30V$	-	75	-	pF
C_{res}	Reverse Transfer Capacitance	$f=1.0MHz$	-	50	-	pF

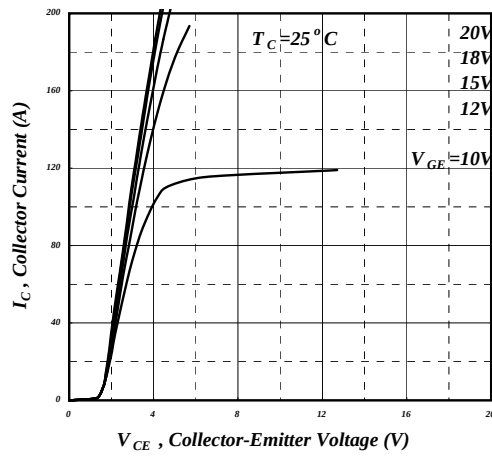


Fig 1. Typical Output Characteristics

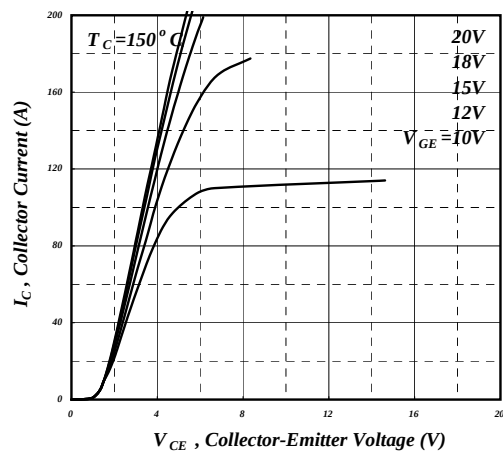


Fig 2. Typical Output Characteristics

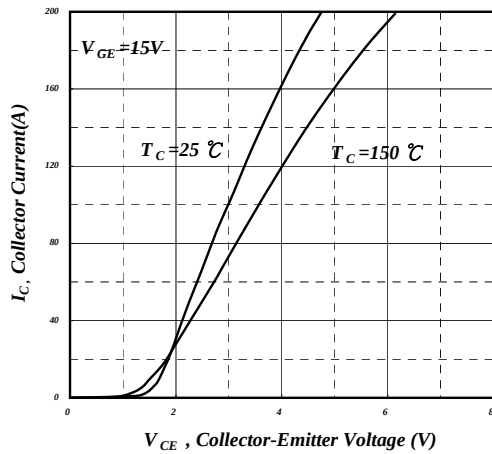


Fig 3. Typical Saturation Voltage Characteristics

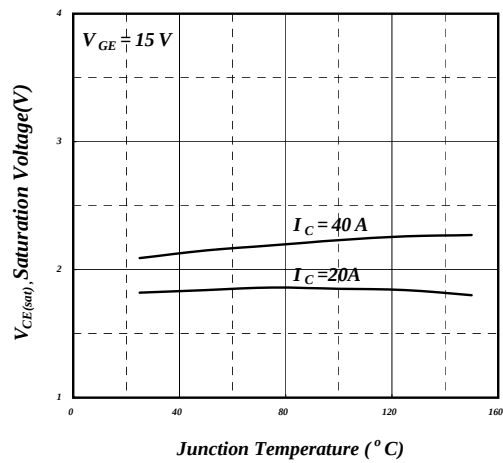


Fig 4. Typical Collector- Emitter Voltage v.s. Junction Temperature

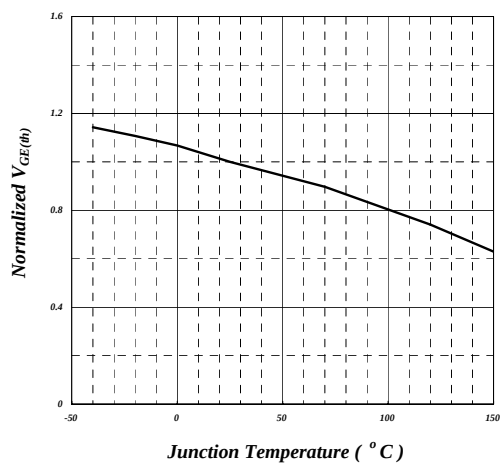


Fig 5. Gate Threshold Voltage v.s. Junction Temperature

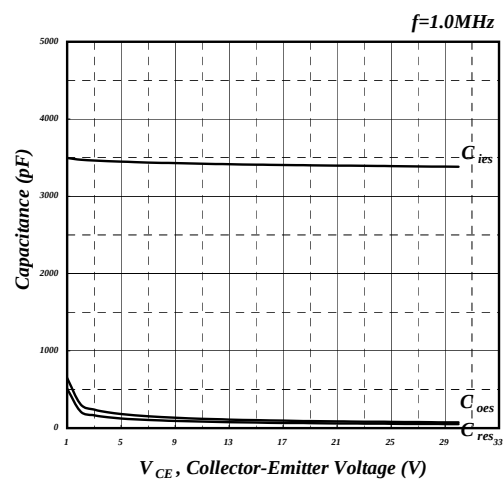


Fig 6. Typical Capacitance Characteristics

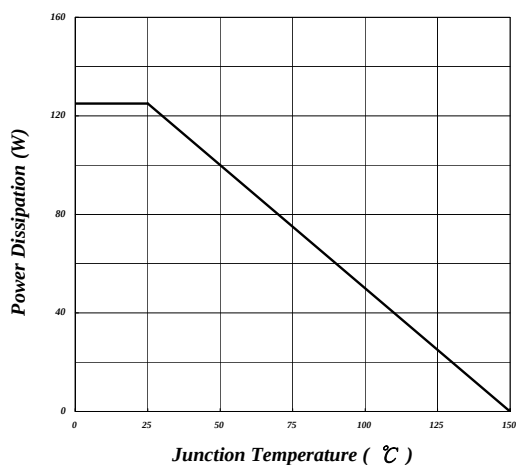


Fig 7. Power Dissipation vs. Junction Temperature

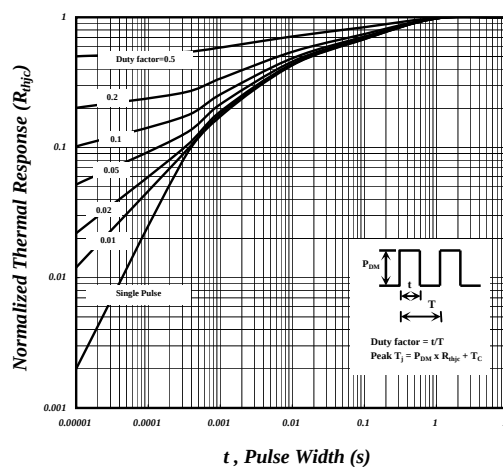


Fig 8. Effective Transient Thermal Impedance

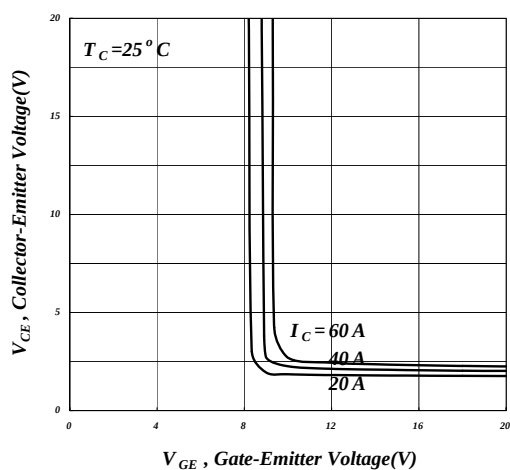


Fig 9. Saturation Voltage vs. V_{GE}

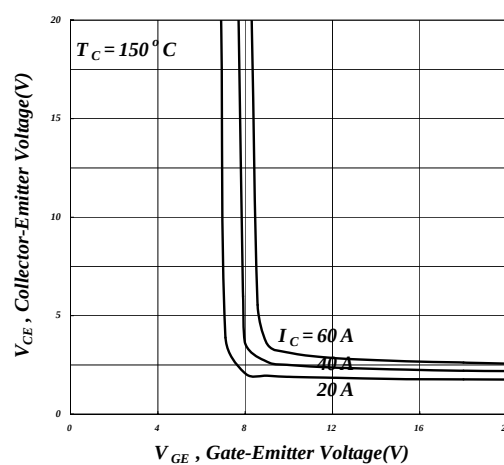


Fig 10. Saturation Voltage vs. V_{GE}

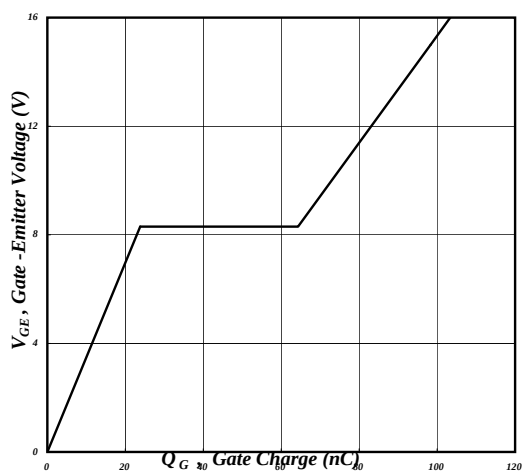


Fig 11. Gate Charge Characteristics

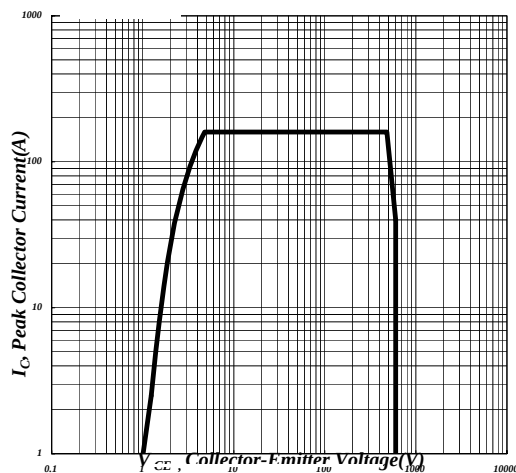


Fig 12. Turn-off SOA



AP20GT60W

MARKING INFORMATION

